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September 2013



### FGP10N60UNDF 600 V, 10 A Short Circuit Rated IGBT

#### Features

- Short Circuit Rated 10 us
- High Current Capability
- High Input Impedance
- Fast Switching
- RoHS Compliant

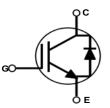
### **General Description**

Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverterdriven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.

### Applications

· Sewing Machine, CNC, Home Appliances, Motor Control





#### **Absolute Maximum Ratings**

Symbol	Description           Collector to Emitter Voltage		Ratings	Unit V	
V <sub>CES</sub>			600		
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V	
1	Collector Current	@ T <sub>C</sub> = 25°C	20	A	
IC	Collector Current	@ T <sub>C</sub> = 100°C	10	A	
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	30	A	
IF	Diode Forward Current	@ T <sub>C</sub> = 25°C	10	А	
	Diode Forward Current	@ T <sub>C</sub> = 100°C	5	A	
PD	Maximum Power Dissipation	@ TC = 25oC	139	W	
	Maximum Power Dissipation	@ TC = 100oC	56	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

#### **Thermal Characteristics**

Symbol	nbol Parameter		Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.9	°C/W
$R_{\theta JC}(Diode)$	HJC(Diode) Thermal Resistance, Junction to Case - 3.5		°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	62.5	°C/W

Notes:

2: Mountde on 1" square PCB (FR4 or G-10 material)

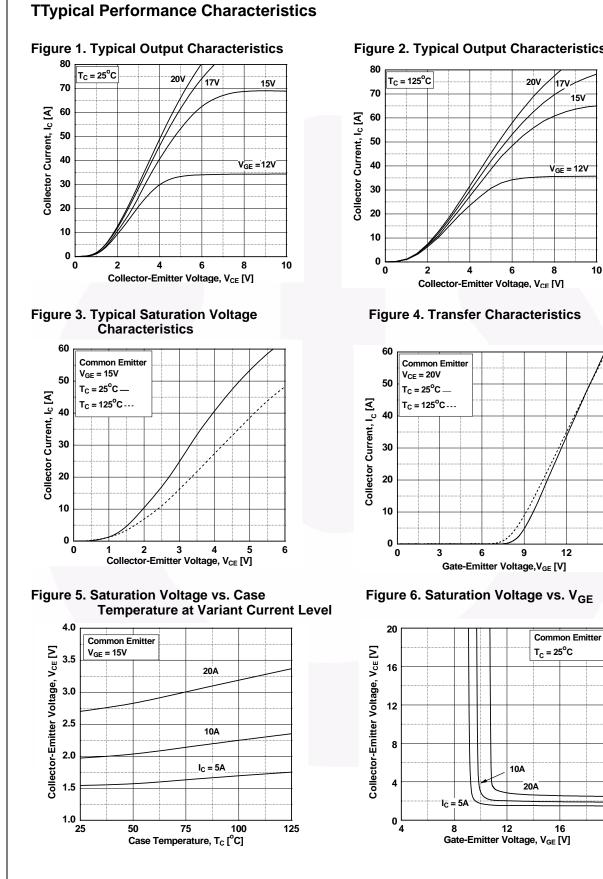
		Package	ackage Reel Size		Tape Width		Quantity	
		TO-220	-	-		50ea		
Electric	al Char	acteristics of t	he IGBT T <sub>c=2</sub>	5°C unless otherwise noted				_
Symbol		Parameter	Test	Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics							
BV <sub>CES</sub>		to Emitter Breakdown Vo	oltage V <sub>GE</sub> = 0 V, I	c = 250 μA	600	-	-	V
I <sub>CES</sub>		Cut-Off Current	$V_{CE} = V_{CES}$		-	-	1	mA
I <sub>GES</sub>		age Current	V <sub>GE</sub> = V <sub>GES</sub>		-	-	±10	uA
	toriotion							
On Charac		shold Voltage	I <sub>C</sub> = 10 mA,	$V_{CE} = V_{CE}$	5.5	6.8	8.5	V
5L(ui)			$I_{\rm C} = 10$ A, V <sub>0</sub>		-	2	2.45	V
V <sub>CE(sat)</sub>	Collector	to Emitter Saturation Vo		<sub>GE</sub> = 15 V,	-	2.3	-	V
Dynamic C	haracteris	tics	0			<u> </u>		
C <sub>ies</sub>	Input Cap	acitance				517		pF
C <sub>oes</sub>	Output Ca	apacitance	V <sub>CE</sub> = 30 V <sub>,</sub> f = 1 MHz	$V_{CE} = 30 V, V_{GE} = 0 V,$		65		pF
C <sub>res</sub>	Reverse 1	Transfer Capacitance	f = 1 MHz		-	20		pF
Switching	Characteri	stics						
t <sub>d(on)</sub>	Turn-On [	Delay Time			-	8.0		ns
t <sub>r</sub>	Rise Time	)				6.3		ns
t <sub>d(off)</sub>	Turn-Off	Delay Time	V <sub>CC</sub> = 400 \	/, I <sub>C</sub> = 10 A,	-	52.2		ns
t <sub>f</sub>	Fall Time		$R_G = 10 \Omega$ ,	V <sub>GE</sub> = 15 V,	-	19.1	24.8	ns
Eon	Turn-On S	Switching Loss	Inductive Lo	bad, $T_C = 25^{\circ}C$	-	0.15		mJ
E <sub>off</sub>	Turn-Off S	Switching Loss			-	0.05		mJ
E <sub>ts</sub>	Total Swit	ching Loss			-	0.2		mJ
t <sub>d(on)</sub>	Turn-On E	Delay Time			-	8.1		ns
t <sub>r</sub>	Rise Time	)			-	7.3		ns
t <sub>d(off)</sub>	Turn-Off	Delay Time	V <sub>CC</sub> = 400 \	/, I <sub>C</sub> = 10 A,	-	55.1		ns
t <sub>f</sub>	Fall Time		R <sub>G</sub> = 10 Ω,	V <sub>GE</sub> = 15 V,	-	34.2		ns
E <sub>on</sub>	Turn-On S	Switching Loss		oad, T <sub>C</sub> = 125°C	-	0.22		mJ
E <sub>off</sub>	Turn-Off S	Switching Loss			-	0.08		mJ
E <sub>ts</sub>	Total Swit	ching Loss			-	0.3		mJ
T <sub>sc</sub>	Short Circ	cuit Withstand Time	$V_{CC} = 350 \text{ V}$ $R_G = 100 \Omega$ $T_C = 150^{\circ}\text{C}$	/, , V <sub>GE</sub> = 15V ,	10	-	- (	μs

<b>Electrical Characteristics of the IGBT</b>	T <sub>C</sub> = 25°C unless otherwise noted
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Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	37		nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 10 A, V <sub>GE</sub> = 1 V	-	5		nC
Q <sub>gc</sub>	Gate to Collector Charge	VGE - 1 V	-	21		nC

### Electrical Characteristics of the Diode T<sub>C</sub> = 25°C unless otherwise noted

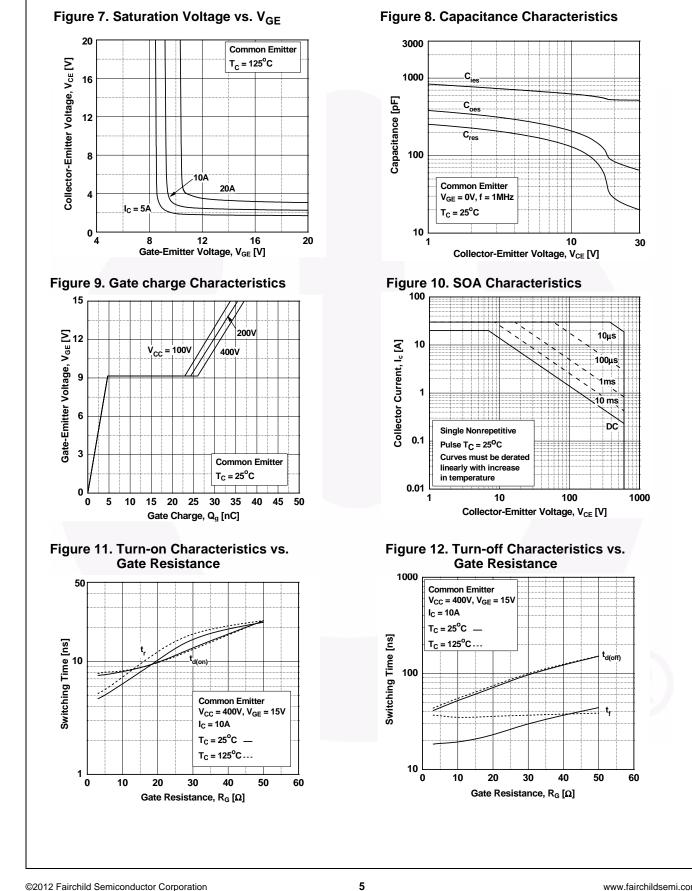
Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V <sub>FM</sub> D	Diode Forward Voltage	I <sub>F</sub> = 10 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.8	2.2	V
		- ····	$T_C = 125^{\circ}C$	-	1.7		
t <sub>rr</sub> Di	Diode Reverse Recovery Time		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	37.7		ns
·rr			$T_{C} = 125^{\circ}C$		78.9		
Q <sub>rr</sub>	Diode Reverse Recovery Charge		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	75		nC
~11			$T_{C} = 125^{\circ}C$	-	221		



**Figure 2. Typical Output Characteristics** 

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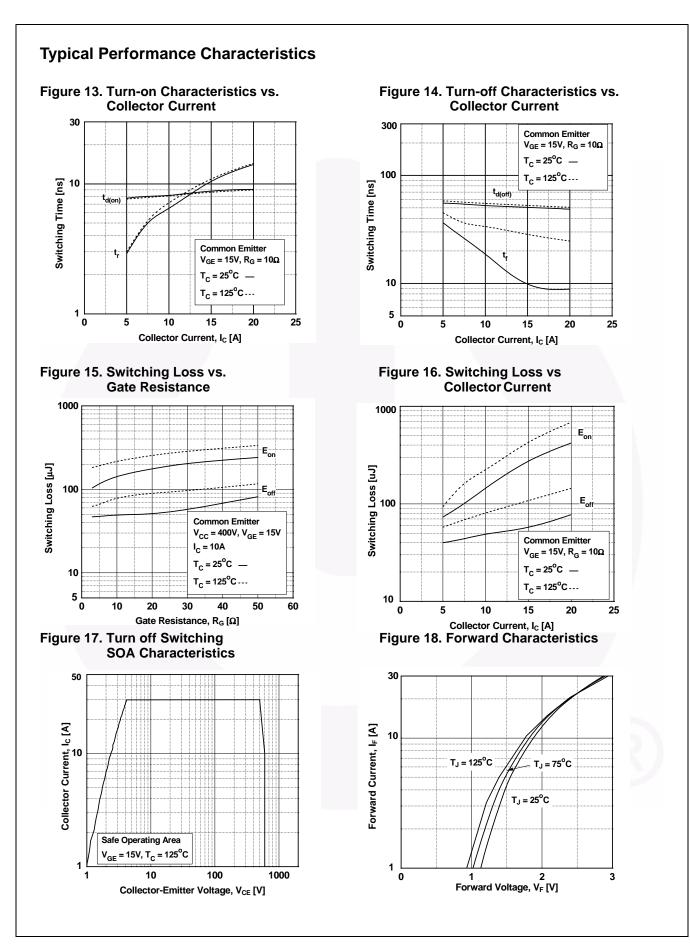
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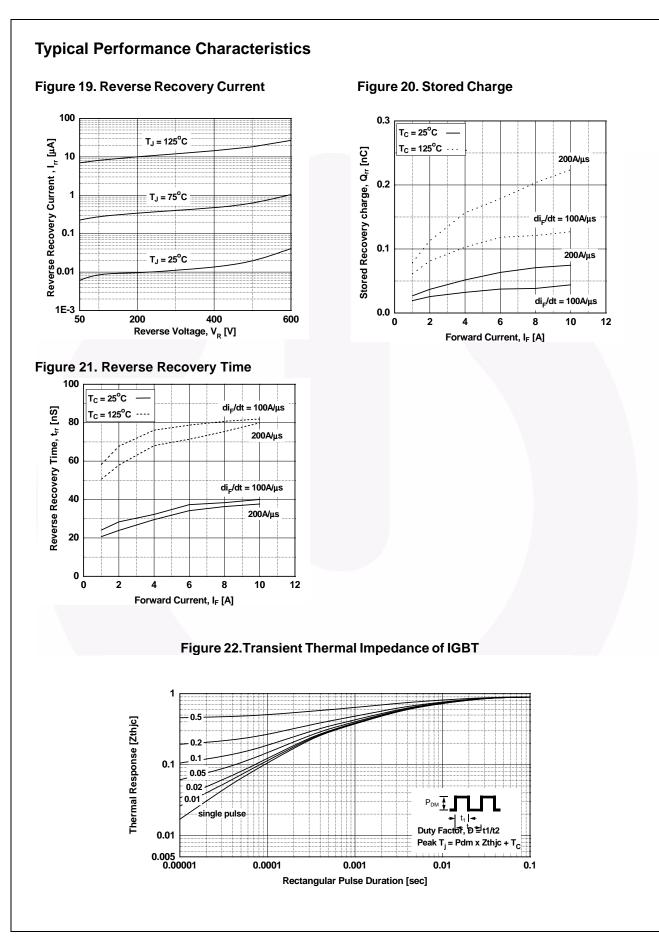
**Typical Performance Characteristics** 

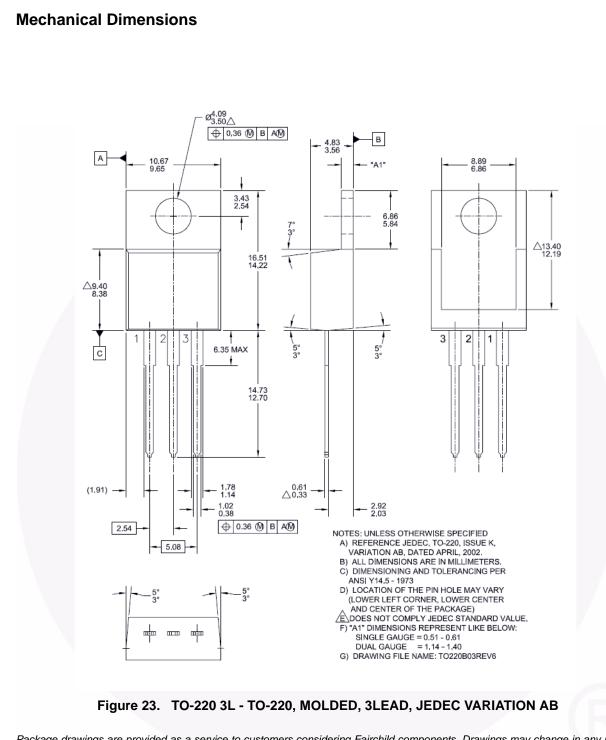
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FGP10N60UNDF — 600 V, 10 A Short Circuit Rated IGBT



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Dimensions in Millimeters

FGP10N60UNDF — 600 V, 10 A Short Circuit Rated IGBT



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